

Fundamentals of Nanoelectronics

ECE495 - Session 30, Nov 9, 2009

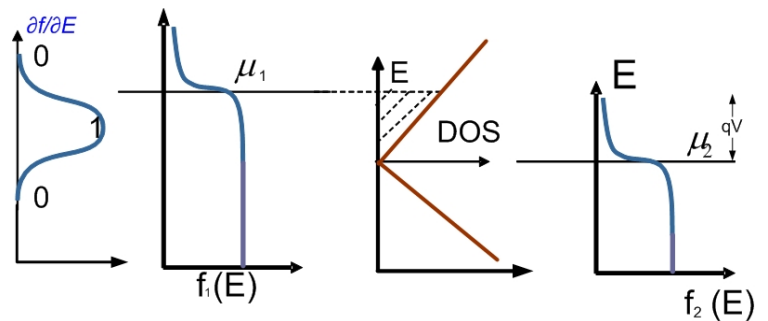
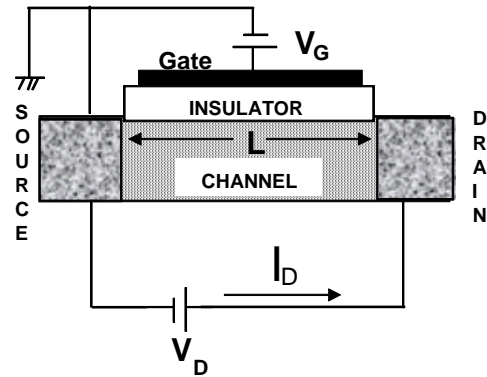
Transmission Coefficient

Professor Supriyo Datta

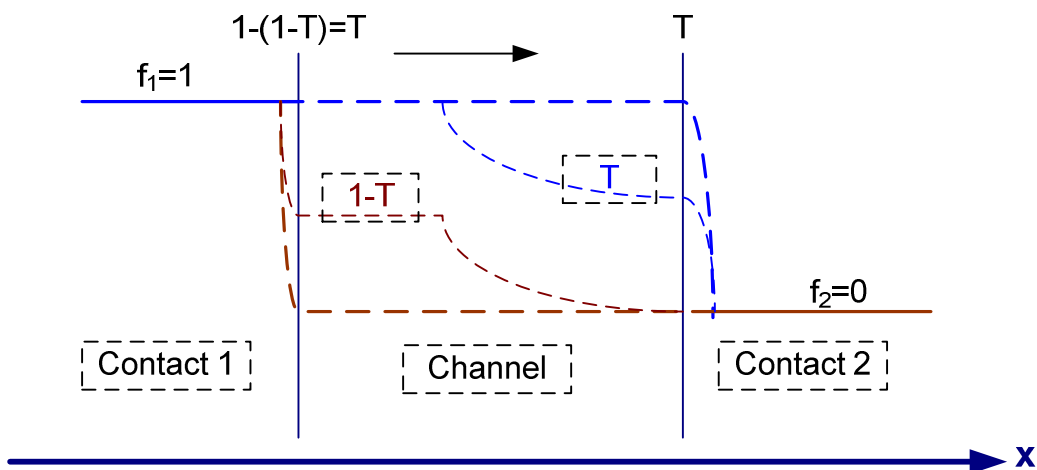
Class notes taken by: Mehdi Salmani

Review

$$I = \frac{q}{h} \int \frac{dE}{qV} M(E) (f_1^+ - f_2^-)$$

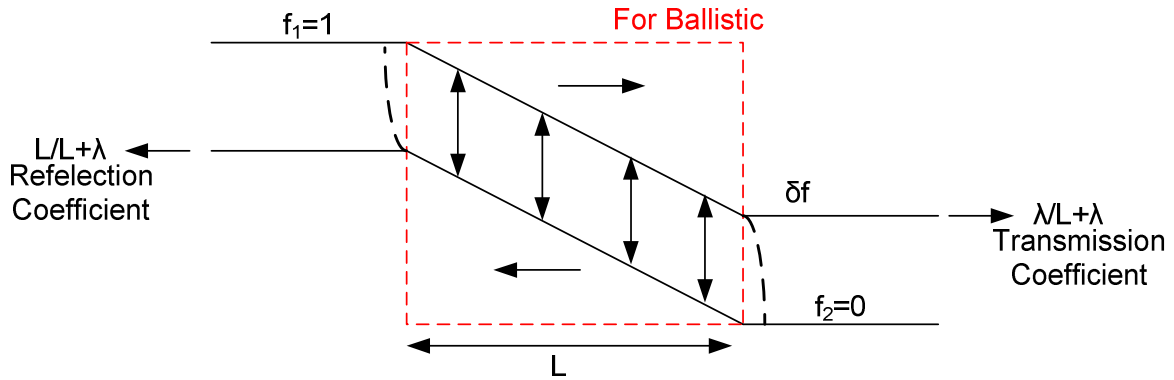


Transmission Coefficient



T , the differences are the same in both contacts and over the channel. This is because of steady state.

The second lane (f_2) is not effective on current when T is 1.



$\frac{\Delta x}{\lambda}$ shows probability of number of scattering.

$$\Delta f^+ = -f^+ \frac{\Delta x}{\lambda} + f^- \frac{\Delta x}{\lambda} \Rightarrow \frac{\partial f^+}{\partial x} = -\frac{f^+ - f^-}{\lambda} \quad (I) \text{ and we can say } \frac{\partial f^-}{\partial x} = -\frac{f^+ - f^-}{\lambda}$$

As it is clear $\frac{\partial}{\partial x}(f^+ - f^-) = 0$ (the distance between f^+ and f^- is fixed along x) then

$$f^+ - f^- = \delta f \quad (II)$$

$$\text{From (I) and (II)} \quad -\frac{1 - \delta f}{L} = -\frac{\delta f}{\lambda} \Rightarrow \lambda - \lambda \delta f = L \delta f \Rightarrow \delta f = \frac{\lambda}{L + \lambda}$$

For ballistic regime ($L \ll \lambda$): $\delta f \cong \frac{\lambda}{\lambda} = 1$

$$I = \frac{q}{h} \int dE M(E) \underbrace{(f^+ - f^-)}_{\frac{\lambda}{L + \lambda}(f_1 - f_2)}$$

$$I = \frac{q}{h} \int dE \frac{M\lambda}{L} \underbrace{(f_1 - f_2)}_{-\frac{\partial f}{\partial E} qV} \quad \text{For long devices}$$

$$G = \frac{\sigma A}{L} \quad \text{and} \quad G = \frac{M\lambda}{L} \Rightarrow \sigma = M \frac{\lambda}{A} \quad \text{M is from Quantum Mechanic}$$